NSN 5961-01-201-9572

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-201-9572

Inclosure Material:

Metal

Overall Length:

0.915 inches

Mounting Facility Quantity:

1

Internal Configuration:

Field effect

Mounting Method:

Threaded stud

Overall Width Across Flats:

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 on-state drain to source voltage and 20.0 gate to source voltage

Current Rating Per Characteristic:

24.00 amperes drain current and 60.00 amperes off-state current, peak

Power Rating Per Characteristic:

150.0 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0